

OptiMOS™ 5 Power MOS Transistor Chip

IPC331N15NM5R

Туре	V _{(BR)DSS}	R _{DS(on)}	Die size	Die-thickness
IPC331N15NM5R	150 V	$2.9~\text{m}\Omega$	7.05 x 4.7 mm ²	246 μm

Description

- N-channel enhancement mode
- For dynamic characterization refer to the datasheet of IPP051N15N5¹⁾
- Electrostatic Discharge Sensitive Device according to JEDEC
- Die bond: suitable for soft solder
- Wire bond: Al wedge recommended
- Backside metallization: NiAg system
- Frontside metallization: AlCu system
- Passivation: imide

1 Electrical Characteristics on Wafer Level

at T_i = 25 °C, unless otherwise specified.

Parameter	Symbol	Value			Unit	Conditions
		min.	typ.	max.		
Drain-source breakdown voltage	$V_{(BR)DSS}$	150	-	-	V	$V_{GS} = 0 V$
						$I_D = 1 \text{ mA}$
Gate threshold voltage	$V_{GS(th)}$	3.0	3.8	4.6	V	$V_{DS} = V_{GS}$
						Ι _D = 290 μΑ
Zero gate voltage drain current	I _{DSS}	-	0.1	1	μΑ	$V_{GS} = 0 V$
						V _{DS} = 120 V
Gate-source leakage current	I _{GSS}	-	1	100	nA	V _{GS} = 20 V
						$V_{DS} = 0 V$
Drain-source on-resistance	R _{DS(on)}	-	2.9 ²⁾	1003)	mΩ	V _{GS} = 10 V
						I _D = 2 A
Gate resistance	R_{G}	5.5	14	22.5	Ω	-
Reverse diode forward on-voltage	V_{SD}	-	0.65	0.9	V	V _{GS} = 0 V
						I _F = 1 A
Avalanche energy, single pulse	E _{AS}	-	704)	-	mJ	$I_D = 38 \text{ A}, R_{GS} = 25 \Omega$

¹⁾ IPP051N15N5 dynamic characterization does not include the internal added R_G

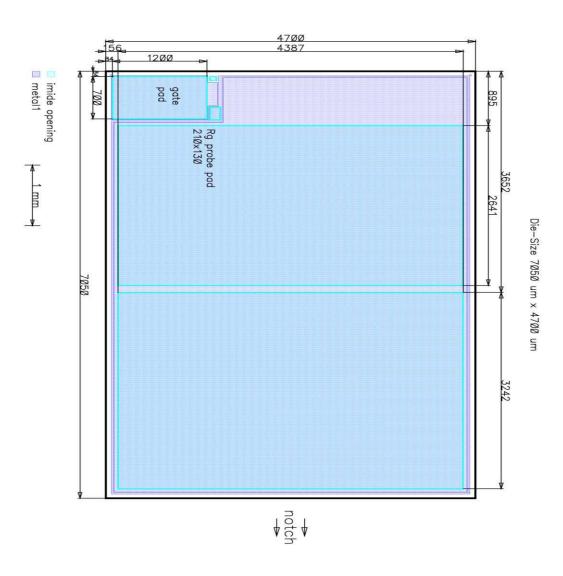
 $^{^{2)}}$ typical bare die $R_{DS(on)}$; V_{GS} = 10 V

³⁾ limited by wafer test-equipment

⁴⁾ Wafer tested.



2 Chip Layout



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Revision History

IPC331N15NM5R

Revision: 2019-04-29, Rev. 2.0

Previous Revision

1 Teviodo i Cevioloti					
Revision	Date	Subjects (major changes since last revision)			
2.0	2019-04-29	Release of final version			

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